

TABLE. Calculated and Measured* Structure Factors

hkl	Φ	Φ_0	hkl	Φ	Φ_0	hkl	Φ	Φ_0
a) $l = 4n$								
10.4	+1.18	0.65	20.52	-0.20	0.58			
10.12	+0.36	0	20.60	+5.13	5.01	13.24	+5.11	4.16
10.16	-0.43	0.76	20.64	+0.10	0.28	13.28	+0.08	0.45
10.24	+12.16	10.30	21.4	+0.65	0.45	13.40	+0.40	0.79
10.28	+0.18	0.22	21.12	+0.20	0	13.48	+0.13	0
10.32	-0.32	0.36	21.24	+7.03	6.13	13.60	+3.70	2.68
10.40	+1.47	1.13	21.28	+0.12	0.17	13.64	+0.07	0.74
10.44	+0.64	0.75	21.32	-0.22	0.26	40.12	+0.13	0
10.48	+0.20	0	21.40	+0.49	0.80	40.24	+4.59	3.66
10.52	-0.23	0.95	21.44	+0.47	0.66	40.60	+2.60	1.91
10.4	-0.46	0.26	21.48	+0.15	0	40.12	+4.79	3.85
10.12	+15.16	13.40	21.52	-0.17	0.55	40.24	+0.13	0
10.16	+0.24	0.34	21.60	+4.59	3.86	40.60	+0.09	0.22
10.24	+0.30	0.26	21.64	+0.09	0.59	32.12	+0.13	0
10.28	+0.82	1.08	21.84	+0.09	0.22	32.24	+0.04	3.36
10.32	+0.80	0.90	21.88	+0.09	0.67	32.48	+0.10	0
10.40	-0.29	0.22	12.4	-0.26	0.19	32.60	+3.21	2.71
10.44	+0.14	0.17	12.12	+7.63	9.50	23.12	+4.27	3.66
10.48	+7.42	6.36	12.24	+0.19	0.55	23.24	+0.12	0
10.52	+0.12	0.50	12.28	+0.55	0.95	23.48	+3.37	2.86
11.0	+11.82	11.10	12.32	+0.57	0.69	23.60	+0.10	0
11.16	+0.80	0.90	12.40	-0.20	0.32	410	+4.08	3.48
11.20	+0.80	0.65	12.44	+0.10	0.14	41.36	+3.60	3.06
11.36	+7.87	8.15	12.48	+5.35	4.60	50.12	+3.51	3.12
11.40	+0.15	0.92	12.52	+0.09	0.84	50.24	+0.10	0
11.52	+0.54	0.97	12.60	+0.13	0	50.48	+3.01	2.39
11.56	+0.47	0.77	12.64	+0.40	0.90	50.12	+0.10	0
11.72	+4.41	3.95	12.84	+3.37	2.49	50.24	+3.41	2.59
11.76	+0.08	1.00	12.88	+0.07	0.52	50.48	+0.09	0.24
20.4	+0.32	0.32	30.0	+6.91	6.03	330	+3.40	3.04
20.8	+0.58	0.30	30.16	+0.56	0.79	33.36	+3.18	2.88
20.12	+9.78	11.30	30.20	+0.53	0.70	42.12	+3.28	2.64
20.24	+0.24	0	30.36	+0.31	1.46	42.24	+0.09	0
20.28	+0.71	1.05	30.40	+0.10	0.85	42.48	+2.28	2.34
20.32	+0.64	0.77	30.52	+0.40	0.77	24.12	+0.09	0.26
20.40	-0.31	0.54	30.56	+0.40	0.45	24.24	+3.19	2.72
20.44	+0.14	0.20	30.72	+3.60	2.96	24.48	+0.09	0
20.48	+6.07	5.62	30.76	+0.05	0.86	51.12	+0.10	0
20.52	+0.11	0.30	220	+5.83	5.20	51.24	+3.03	2.83
20.60	+0.15	0	22.16	+0.22	0.79	51.48	+0.09	0
20.64	+0.42	1.23	22.36	+0.28	1.65	15.12	+3.09	3.04
20.4	+0.80	0.41	31.12	+5.49	4.75	15.24	+0.10	0
20.8	+0.80	0.41	31.24	+0.14	0	15.48	+2.70	1.48
20.12	+0.26	0	31.28	+0.41	0.70	600	+2.82	2.34
2.024	+8.68	8.20	31.40	-0.16	0.35	43.12	+0.09	0
2.028	+0.15	0.21	32.48	+4.20	3.12	34.12	+2.70	2.13
2.032	-0.27	0.32	31.60	+0.11	0	520	+2.68	2.04
2.040	+0.57	0.93	31.64	+0.29	0.96	52.36	+2.43	1.90
20.44	+0.56	0.76						
20.48	+0.17	0	13.12	+0.15	0			

b) $l = 2n$

10.10	-3.54	3.61	01.22	-3.35	1.71	11.38	+0.63	1.85
01.10	-1.27	1.30	10.26	+0.97	0.63	20.26	+1.96	2.35
10.14	+3.90	4.25	01.26	+2.75	1.80	02.26	+0.70	0.85
01.14	+1.22	1.32	10.50	+1.86	1.97	21.50	+1.37	1.41
10.22	-1.05	0.53	01.50	+0.58	0.61	12.50	+0.43	0.44

c) $l \neq 2n$

hkl	A	B	Φ	cos α	sin α	Φ_0
109	-1.21	-1.21	1.71	0.708	0.708	1.3
10.15	+0.79	-0.79	1.21	0.707	1.707	1.71
10.19	-0.45	+0.45	0.63	0.712	0.712	0.58
0.19	+0.32	+0.32	0.44	0.714	0.714	0.35
01.15	+0.28	-0.28	0.40	0.714	0.714	0.62
01.19	-0.59	+0.59	0.84	0.708	0.708	0.76

* As modified by dynamic corrections.

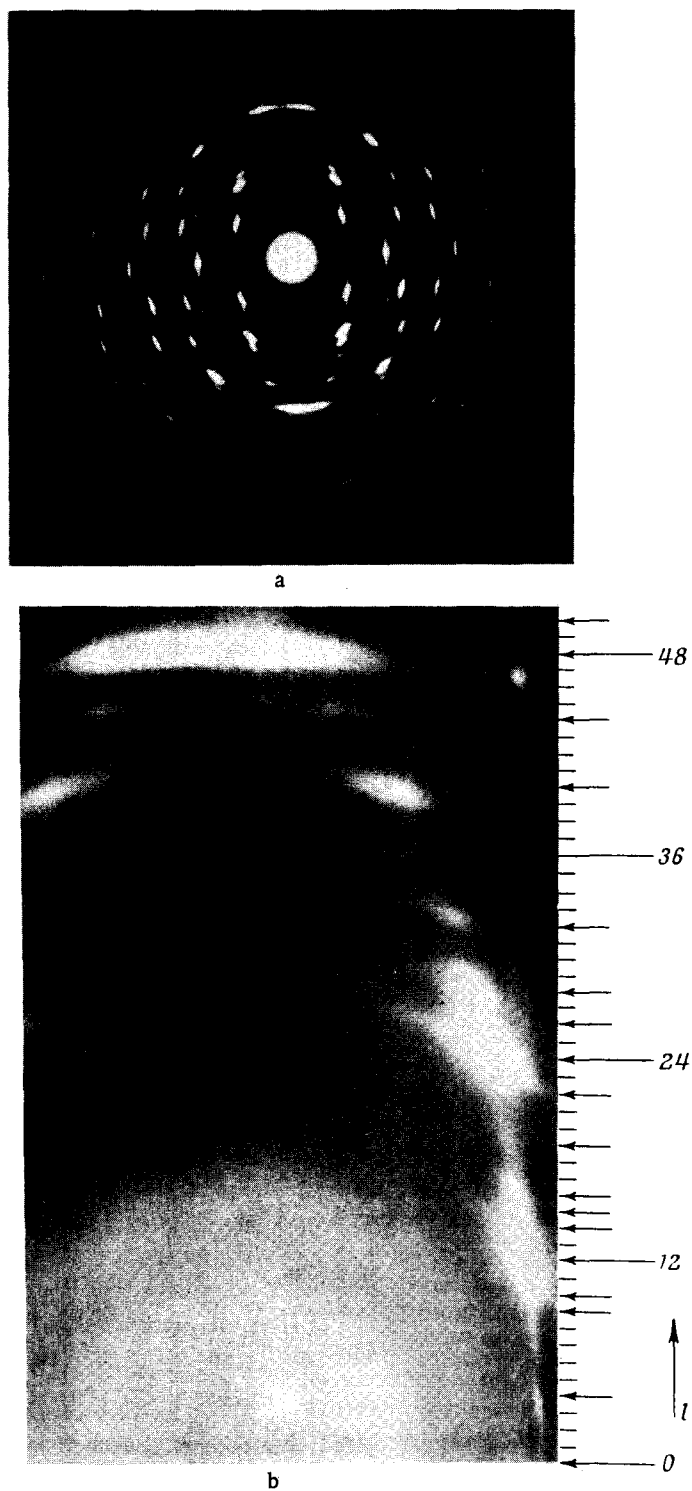


Fig. 2. a) Oblique-texture pattern from phase II of PbBi_4Te_7 ; b) the first $\bar{1}01l$ ellipse enlarged. The reflections are indicated by arrows.

$$c' = \frac{c_I}{3} = \frac{c_{II}}{12} = 5,97 \text{ \AA}.$$

The cell contains four sets each of nine layers (36 layers in all).

Each layer is $71.7/36 = 1.98 \text{ \AA}$ thick (i. e., about 2 \AA), which is characteristic of other semiconductor phases containing Bi and Te [5, 6].

We used Φ^2 and Φ series in the analysis of structure II.

The intensities of reflections on the oblique-texture patterns were measured visually and by means of a microphotometer [6]; the observed intensities were converted to the structure factors by means of the formula [7]:

$$\Phi_{hkl}^2 = \frac{I_{hkl}}{pd_{hko} \cdot d_{hkl}}. \quad (3)$$

A dynamic correction was applied [8]; the mean size of the scattering regions was found to be 400 \AA.

The superlattice reflections for structure II were much weaker than the reflections for structure I, which is described by (2), so the superlattice must be based on four sets of type (2), but these must all differ slightly. The Φ^2 and Φ constructions showed that the differences lie in the distribution of the Pb atoms over the layers A₂B₂C₂A₃ (2) (Fig. 1), in which the atoms are uniformly distributed in structure I. These differences in distribution give rise to slight differences in the scattering power of the sets relative to that power for I or for any given power for II.

Structure II gives reflections with $l \neq 4n$ as a result of these changes in scattering power; we may consider structure I (disordered) as a zero matrix (see [9]), whose alterations are responsible for the reflections with $l \neq 4n$.

A Φ^2 series [an A(00z) section] constructed from reflections with $l = 4n$ gave almost exactly the picture found for structure I; the complete A(00z) section (Fig. 3a) is not very different, because the reflections with $l \neq 4n$ are relatively weak. The complete picture has peaks separated by 5.97 \AA (every third layer), which confirms that the packing is cubic.

The most reliable information on the changes is found from the A(00z) synthesis from the superlattice reflections only (Fig. 3b); this is a component part of Fig. 3a. Most of these reflections have l even; the table shows that few have l odd. This indicates that the four-set structure has a two-set substructure; for this reason, the component derived from the odd l is shown separately in Fig. 3b.

The superlattice synthesis gives a strong peak at $c_{II}/2$ on account of the substructure; there is a minimum at $c_{II}/4$, which shows that the distance between identical points in adjacent sets is $c_{II}/4 = c_I$, which means that the distributions are entirely different (other distances of $c_{II}/4$ would otherwise occur). The strongest peak lies at $c_{II}/12 = 5.97 \text{ \AA}$, which corresponds to the distance between layers separated by two others. The

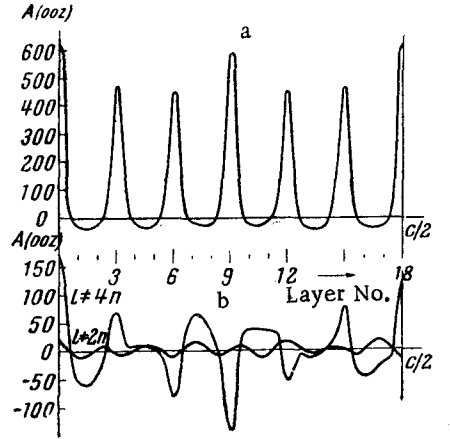
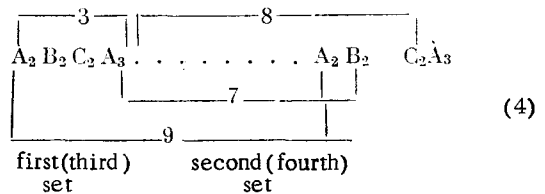


Fig. 3. A(00z) section (a) and components thereof as constructed from reflections with $l \neq 4n$ and $l \neq 2n$.

peak for the fifteenth layer is placed symmetrically with respect to the first; the sole explanation for this is as follows. The redistribution occurs within a set of four layers A₂B₂C₂A₃; the distance between such layers in adjacent sets is at least six layers, so the three-layer distance is one within a set, which cannot be other than the A₂-A₃ distance. Then, in one set at least, the Pb atoms populate mainly the A₂ and A₃ layers, leaving the B₂C₂ layers free (the substructure implies that this occurs in every alternate set). If we denote each layer by a number only (then A₁B₁C₁A₂B₂ ... = 0, 1, 2, 3, 4...), these layers are 3 and 6 (first set) and 3 + 18 = 21, 6 + 18 = 24 (third set; Fig. 6).

The next strong peak in Fig. 3b gives a distance of seven or eight layers (also 10-11, which is symmetrically placed). This is clearly a distance between layers in different sets, because the largest distance within a set is that for three layers. If we consider the layers A₂B₂C₂A₃ as two adjacent nine-layer sets:



then the distances of seven and eight layers are A₃-B₂ and A₃-C₂, which automatically gives A₂-B₂ and A₂-C₂ as 10- and 11-layer distances.

The repeat distance of four sets can arise only if the second set differs from the fourth, because the first and third are the same. This is simple to provide if we assume, for example, that the 7- (or 10-) layer distance is that between Pb atoms in the first and second sets, while the 8- (or 11-) layer distance is the same between third and fourth sets. The A(00z) section indicates that the Pb atoms occur preferentially in layers 3 and 6 (first

set), 13 (second set), 21 and 24 (third set), and 32 (fourth set). The differences between these numbers give all the distances between layers observed in Fig. 3b.

This gives us six positions for Pb, whereas the four-set formula $4 \cdot \frac{3}{4} (\text{PbBi}_4\text{Te}_7)$ gives only three Pb for 36 layers. We may suppose that each of these positions is taken with a probability $\frac{1}{2}$ by a Pb atom and also with a probability of $\frac{1}{2}$ by a Te atom. Other possible arrays do not give satisfactory agreement with the observed superlattice intensities, so the above model was used. There is a further point here that has been glossed over so far. The Φ^2 series of Fig. 3b in principle gives only distances between atoms lying on the same vertical line, such as A-B, B-B, and C-C. These distances are ascribed to layers A-B, A-C, and so on in (4). The reason is that the resolving power of the Φ^2 series in the horizontal plane is small. One might assume that the cubic packing law is violated in the second set [see (4)], the order being B_2A_2 instead of A_2B_2 . The seven-layer distance would then be between A_3 in the first set and A_2 in the second; the same applies to the fourth set (permutation $C_2A_3 \rightarrow A_3C_2$).

We used the series $\varphi(00z)$ and $\varphi(\frac{1}{3} \frac{2}{3} z)$ in the subsequent analysis; the space group is $D_{3d}^3 - \bar{P}3m1$, which has centers of symmetry at 000 and $00\frac{1}{2}$. Now (2) and (4) indicate that these centers coincide with the centers of the first and third sets, which lie between B_2C_2 layers. The calculations are made much simpler if we bear in mind that each set has the symmetry D_{3d}^3 (if we neglect the redistribution of the Pb atoms). This means that the structure factors for $l = 4n$ are precisely those for structure I; all are real. The reflections with $l \neq 4n$ arise from the randomly distributed Pb atoms among the Te atoms in layers 3, 6, 13, 21, 24, and 32. The zero matrix does not give reflections with $l \neq 4n$, but the modified structure has the above layers filled by effective difference atoms $(\frac{1}{2} \text{Pb} + \frac{1}{2} \text{Te}) - \text{Te} = \frac{1}{2}(\text{Pb} - \text{Te})$, which gives rise to an effective atomic scattering factor for electrons of $f' = [f(\text{Pb}) - f(\text{Te})]/2$ for the reflections with $l \neq 4n$.

We have given the layers the above logical numbering, for which the origin (000) lies at the center of atom B_{II} in the first set and the z (the coordinates of the other atoms) are $N/36$ (in which N is the number of the set); on this basis we have calculated the superlattice reflections from the formulas for group C_{3v}^1 , whose points have coordinates $00 \frac{3}{36}$; $00 \frac{6}{36}$; $\frac{1}{3} \frac{2}{3} \frac{3}{36}$; $00 \frac{21}{36}$; $00 \frac{24}{36}$; $\frac{2}{3} \frac{1}{3} \frac{32}{36}$. These formulas take the form

$$\begin{aligned} A_{hkl} = f & \left[\cos 2\pi \frac{l}{12} + \cos 2\pi \frac{l}{6} \right. \\ & + \cos 2\pi \frac{7l}{12} + \cos 2\pi \frac{2l}{3} \\ & + \cos \pi i \cdot \cos \pi \left(\frac{k-h}{3} + \frac{13l}{18} \right) \\ & \left. + \cos \pi i \cdot \cos \pi \left(\frac{h-k}{3} + \frac{16l}{18} \right) \right], \quad (5) \end{aligned}$$

while the analogous expression for B_{hkl} has all cosines (except $\cos \pi i$) replaced by sines. The table gives the signs and phases so calculated, as well as the corresponding $|\Phi_0|$:

	A_I	B_I	C_I	A_2	B_2	C_2	A_3	B_3	C_3
Set I	Bi	Te	Bi	$\text{Te}_{1/2}$	Te *	Te	$\text{Te}_{1/2}$	Bi	Te
				$\text{Pb}_{1/2}$				$\text{Pb}_{1/2}$	
Set II	Bi	Te	Bi	Te	$\text{Te}_{2/3}$	$\text{Te}_{1/6}$	Te	Bi	Te
					$\text{Pb}_{1/2}$	$\text{Pb}_{1/6}$			
Set III	Bi	Te	Bi	$\text{Te}_{1/2}$	Te *	Te	$\text{Te}_{1/2}$	Bi	Te
				$\text{Pb}_{1/2}$	$\text{Pb}_{1/2}$	$\text{Te}_{1/6}$	$\text{Pb}_{1/2}$		
Set IV	Bi	Te	Bi	Te	$\text{Te}_{1/6}$	$\text{Pb}_{1/2}$	Te	Bi	Te
					$\text{Pb}_{1/6}$				

(Asterisks denote the centers of symmetry in group D_{3d}^3). The hkl and $\bar{h}k\bar{l}$ reflections are fused in these texture patterns from PbBi_4Te_7 although the structure factors are always different. The contribution from each $|\Phi_0|$ in each pair was calculated theoretically.

Figure 4 shows $\varphi(00z)$ with its components as broken lines; that for $l = 4n$ is the main one, while that for $l \neq 4n$ arises from the altered distribution of the Pb. This reveals atoms whose x and y coordinates are 0. The result for $l \neq 4n$ shows clearly the altered distribution of

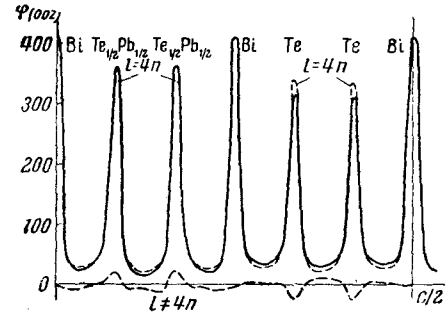


Fig. 4. One-dimensional $\delta(00z)$ section (full line), and components (broken lines) constructed from reflections with $l = 4n$ and $l \neq 4n$.

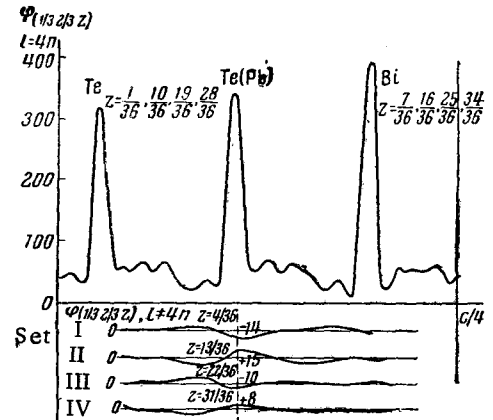


Fig. 5. One-dimensional $\varphi(\frac{1}{3} \frac{2}{3} z)$ section derived from the reflections with $l \neq 4n$, together with the contributions from those reflections for each of the four sets.

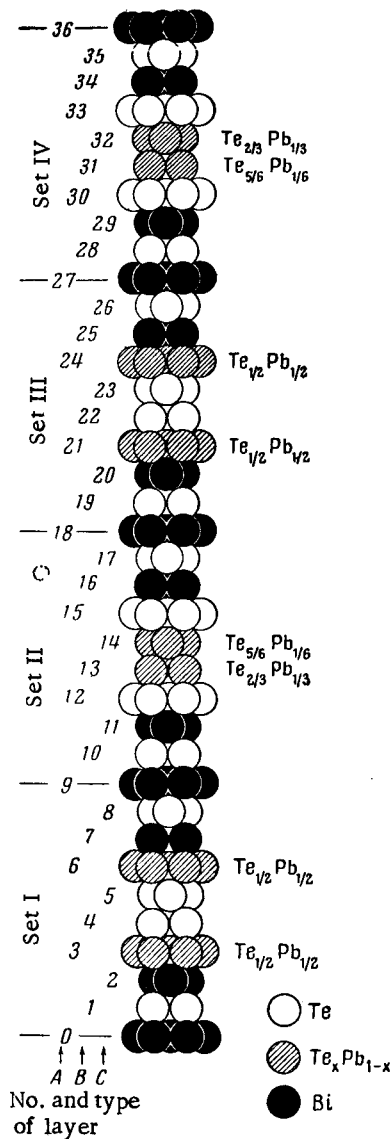


Fig. 6. Superlattice II of PbBi_4Te_7 .

the Pb in positions $\frac{3}{36}$, $\frac{6}{36}$ ($\frac{21}{36}$, $\frac{24}{36}$) and the positions $\frac{12}{36}$; $\frac{15}{36}$ ($\frac{30}{36}$, $\frac{33}{36}$) thus left to the Te. The peak heights for the synthesis (full line) correspond precisely to the relation Bi, $\frac{1}{2}$ (Pb + Te), Te. (The heights of the middle peaks indicate a Pb content of 49%.)

Figure 5 shows $\varphi(\frac{1}{3}, \frac{2}{3}, z)$, as constructed from the reflections with $l = 4n$, with the contribution from those with $l \neq 4n$. The latter shows the predicted reduced Te (Pb) peak heights for the first and third sets, as well as the increase in the second set; there is also a certain increase in the fourth set. This means that we were not quite correct in making the original assumption that the Pb from the $\text{A}_2\text{B}_2\text{C}_2\text{A}_3$ (2) layers in the initial structure passes only to position B_2 in the second set, because the same occurs to a smaller extent in the fourth set. That is, the second set contains in position B_2 ($\frac{1}{3}, \frac{2}{3}, \frac{13}{36}$) rather less than $\frac{1}{2}\text{Pb}$ (about $\frac{1}{3}$), about $\frac{1}{6}$ being in posi-

tion C_2 ($\frac{2}{3}, \frac{1}{3}, \frac{14}{36}$); on the other hand, the fourth set has at position B_2 ($\frac{1}{3}, \frac{2}{3}, \frac{31}{36}$) about $\text{Pb}/_6$ and at C_2 ($\frac{2}{3}, \frac{1}{3}, \frac{32}{36}$) about $\text{Pb}/_3$. Moreover, there is a possible change in the sequence of layers. We consider the model as proven, because the intensities (particularly those of the superlattice reflections) are in satisfactory agreement; again, there are no unexplained peaks on the Fourier synthesis.

To sum up, structure II of PbBi_4Te_7 has some of its layers randomly populated, but these are fewer than in structure I, the structure being as in (6).

The structure shows several repeat periods; the strongest is $c' = 5.97 \text{ \AA} = c_{\text{II}}/12$ (cubic packing), the next being $c_I = c_{\text{II}}/4$ (nine-layer sets), and the third $c_{\text{II}}/2$ (the two-set substructure). Figure 6 shows the structure.

The reliability factor computed from all the tabulated amplitudes is 22%.

All peaks lie almost exactly at the ideal positions (the z are multiples of $\frac{1}{36}$). The shortest distances between atoms in a layer are 4.44 Å; those between atoms in adjacent layers (Bi-Te, Te (Pb)-Te, Te-Te, Te (Pb)-Bi) are 3.32 Å.

Structure II is more highly ordered than structure I, but the order is not complete, although the structure is readily produced under certain conditions; this feature entitles us to consider it as a distinct phase.

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